



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



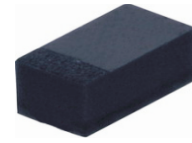
SMD Schottky Barrier Diode



SMD Diodes Specialist

CDBUR40(RoHS Device)

$I_o = 200 \text{ mA}$
 $V_R = 40 \text{ Volts}$

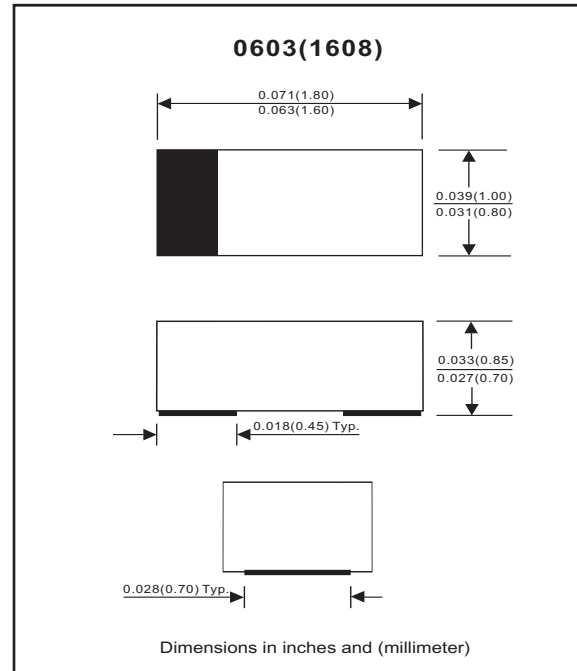


Features

- Low forward voltage.
- Designed for mounting on small surface.
- Extremely thin / leadless package.
- Majority carrier conduction.

Mechanical data

- Case: 0603(1608) standard package, molded plastic.
- Terminals: Gold plated, solderable per MIL-STD-750, method 2026.
- Polarity: Indicated by cathode band.
- Marking code: BC
- Mounting position: Any
- Weight: 0.003 gram(approx.).



Maximum Rating (at $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Peak reverse voltage		V_{RM}			40	V
Reverse voltage		V_R			40	V
RMS reverse voltage		$V_{R(RMS)}$			28	V
Average forward rectified current		I_o			200	mA
Forward current, surge peak	8.3 ms single half sine-wave superimposed on rate load(JEDEC method)	I_{FSM}			0.6	A
Power dissipation		P_D			150	mW
Storage temperature		T_{STG}	-65		+125	$^\circ\text{C}$
Junction temperature		T_j			+125	$^\circ\text{C}$

Electrical Characteristics (at $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F = 1 \text{ mA}$ $I_F = 40 \text{ mA}$	V_F			0.38 1	V
Reverse current	$V_R = 30 \text{ V}$	I_R			0.2	μA
Capacitance between terminals	$f = 1 \text{ MHz}$, and 0 VDC reverse voltage	C_T			5	pF
Reverse recovery time	$I_F=I_R=10 \text{ mA}$, $I_{rr}=0.1 \times I_R$, $R_L=100 \text{ ohm}$	T_{rr}			5	nS

RATING AND CHARACTERISTIC CURVES (CDBUR40)

Fig. 1 - Forward characteristics

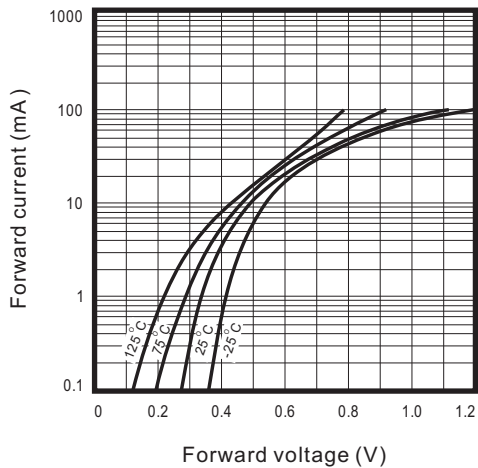


Fig. 2 - Reverse characteristics

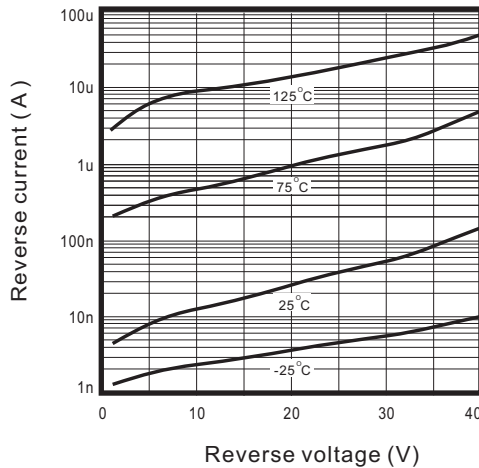


Fig.3 - Capacitance between terminals characteristics

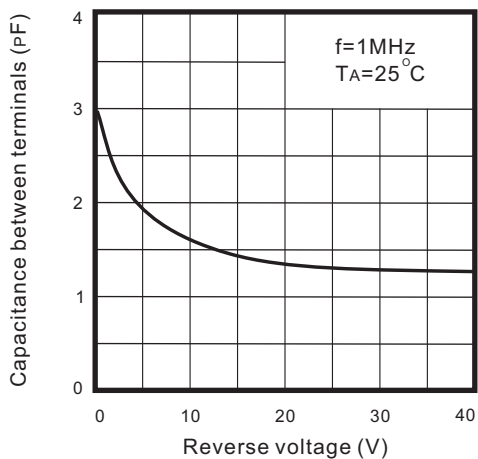
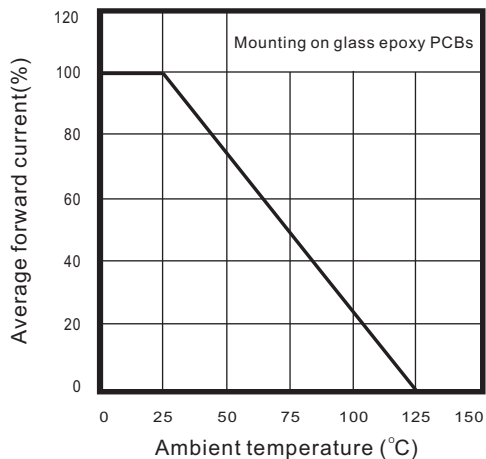
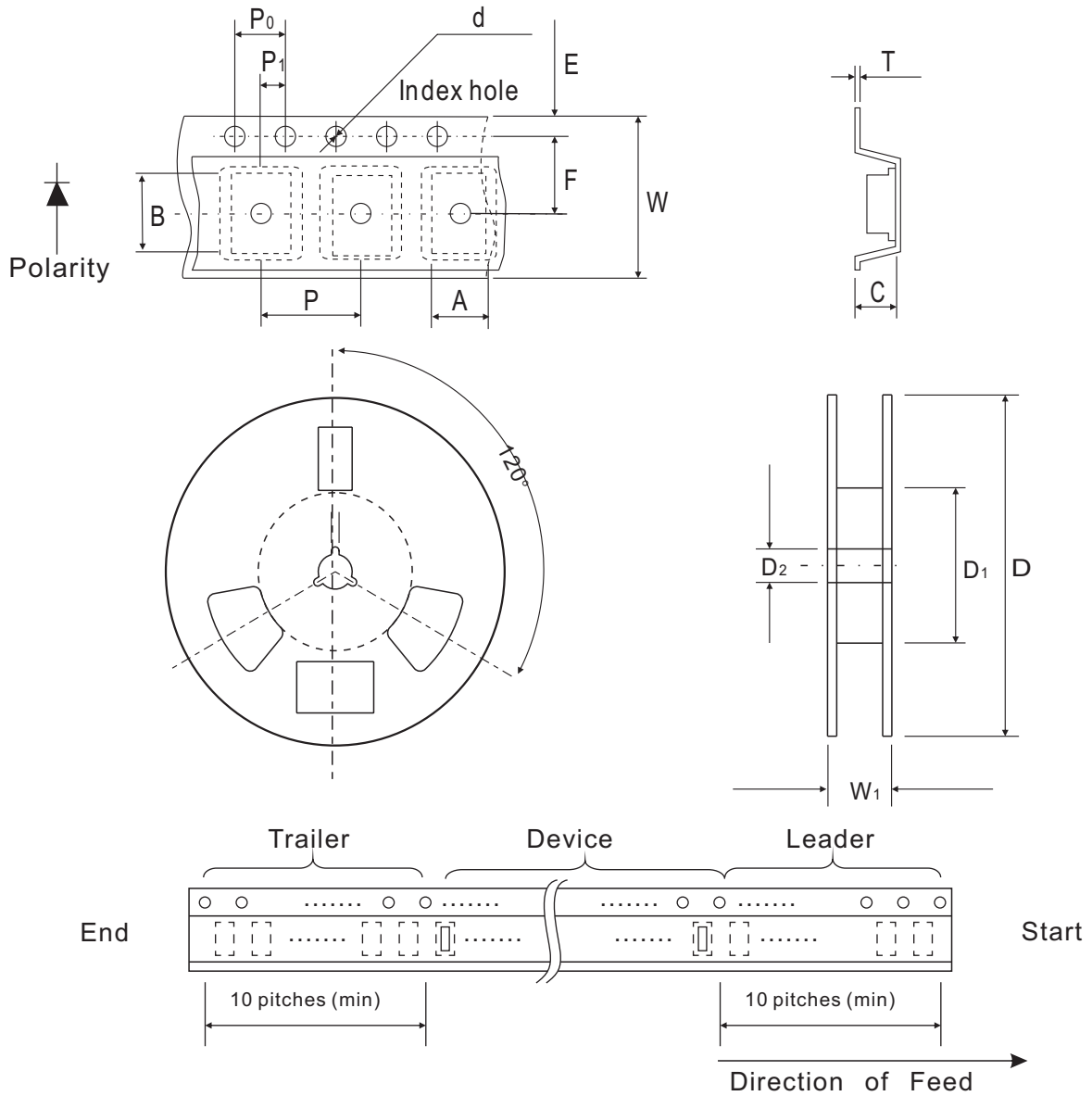


Fig.4 - Current derating curve



Reel Taping Specification



UR/0603	SYMBOL	A	B	C	d	D	D ₁	D ₂
	(mm)	1.00 ± 0.10	1.85 ± 0.10	1.00 ± 0.10	1.55 ± 0.05	178 ± 1	60.0 MIN.	13.0 ± 0.20
	(inch)	0.039 ± 0.004	0.073 ± 0.004	0.039 ± 0.004	0.061 ± 0.002	7.008 ± 0.04	2.362 MIN.	0.512 ± 0.008

UR/0603	SYMBOL	E	F	P	P ₀	P ₁	T	W	W ₁
	(mm)	1.75 ± 0.10	3.50 ± 0.05	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.05	0.23 ± 0.05	8.00 ± 0.20	13.5 MAX.
	(inch)	0.069 ± 0.004	0.138 ± 0.002	0.157 ± 0.004	0.157 ± 0.004	0.079 ± 0.004	0.009 ± 0.002	0.315 ± 0.008	0.531 MAX.

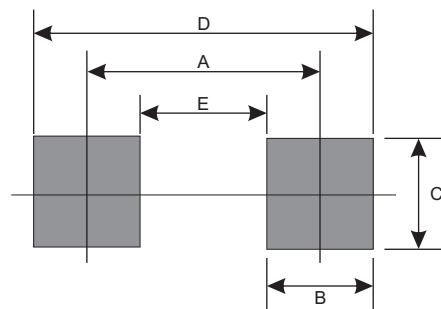
Marking Code

Part Number	Marking Code
CDBUR40	BC



Suggested PAD Layout

SIZE	UR/0603	
	(mm)	(inch)
A	1.25	0.049
B	0.60	0.024
C	1.00	0.039
D	1.85	0.073
E	0.65	0.026



Standard Package

Case Type	Qty per Reel	Reel Size
	(Pcs)	(inch)
UR/0603	4000	7